

BALLARI INSTITUTE OF TECHNOLOGY & MANAGEMENT

(Autonomous Institute under Visvesvaraya Technological University, Belagavi)

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Course Code

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Third Semester B.E. Degree Examinations, April/May 2023

ANALOG ELECTRONIC CIRCUITS

Duration: 3 hrs

Max. Marks: 100

Note: 1. Answer any FIVE full questions, choosing ONE full question from each module.
 2. Missing data, if any, may be suitably assumed

<u>Q. No</u>	<u>Question</u>	<u>Marks</u>	<u>(RBTL:CO:PI)</u>
<u>MODULE – 1</u>			
1.	a. Sketch the equivalent circuit of a diode with characteristics.	04	(2 : 1 : 1.3.1)
	b. Explain the Centre-Tapped full wave rectifier and calculate the efficiency.	08	(2 : 1 : 1.3.1)
	c. Define clippers and explain the working of series clippers circuit along with the waveforms.	08	(2 : 1 : 1.3.1)
OR			
2.	a. Explain the construction and operation of BJT and also write the symbols of pnp and npn transistor.	06	(2 : 1 : 1.3.1)
	b. Explain fixed voltage and adjustable voltage regulators.	08	(2 : 1 : 1.3.1)
	c. With neat diagram explain the transfer and drain characteristics of n-channel MOSFET.	06	(2 : 1 : 1.3.1)
<u>MODULE – 2</u>			
3.	a. Considering the conceptual circuit of common emitter configuration, derive the expressions for g_m , r_π , r_e . Draw the hybrid π - model of a transistor.	08	(2 : 2 : 1.3.1)
	b. A BJT having $\beta = 150$ is biased at a DC collector current 2 mA. Find the value of g_m , r_e , r_π , at bias point.	04	(2 : 2 : 2.1.2)
	c. Obtain the DC conditions for voltage divider bias circuit for a CE-BJT amplifier and give design constraints along with remark on stability of Q.	08	(2 : 2 : 1.3.1)
OR			
4.	a. Explain biasing of MOSFET by fixing V_{GS} .	06	(2 : 2 : 1.3.1)
	b. Draw the small signal equivalent model of MOSFET, derive an expression for voltage gain and transconductance.	08	(2 : 2 : 1.3.1)
	c. What is transconductance and mention the three different expressions used to calculate transconductance.	06	(2 : 2 : 1.3.1)
<u>MODULE – 3</u>			
5.	a. With a neat circuit diagram and ac equivalent circuit, derive the expression for R_{in} , R_o , A_v for a common source amplifier.	08	(2 : 3 : 1.3.1)
	b. Explain the low frequency response of CS amplifier using MOSFET and derive lower cut-off frequency	08	(2 : 3 : 1.3.1)
	c. Explain Junction capacitance in MOSFET.	04	(2 : 3 : 1.3.1)
OR			
6.	a. Obtain the high frequency response of a CS amplifier.	10	(2 : 3 : 1.3.1)
	b. Write a short note on current Mirrors and current steering circuits.	10	(2 : 3 : 1.3.1)

MODULE – 4

7. a. With neat block diagram explain the working of a current series feedback amplifier. Obtain expressions for gain, input resistance and output resistance with feedback **10** (2 :4 : 1.3.1)
- b. Determine the voltage gain, input and output impedance with feedback for a voltage series feedback amplifier having $A = -100$, $R_i = 10 \text{ k}\Omega$, $R_o = 20 \text{ k}\Omega$ for a feedback of (i) $\beta = 1$ and (ii) $\beta = -0.5$. **10** (2 :4 : 2.1.2)

OR

8. a. Explain a class B output stage. Prove that the maximum conversion efficiency of a class B transformer coupled amplifier is 78.5%. **08** (2 :4 : 1.3.1)
- b. Compare different types of power amplifiers. **06** (2 :4 : 1.3.1)
- c. Explain in brief the working of a Class C power amplifier. **06** (2 :4 : 1.3.1)

MODULE – 5

9. a. Explain the working of instrumentation amplifier using transducer bridge and derive the expression for output voltage. **10** (2 :5 : 1.3.1)
- b. Explain the working of a successive approximation type of ADC. **10** (2 :5 : 1.3.1)

OR

10. a. Draw the circuit and frequency response of a first order low pass filter. **06** (2 :5 : 1.3.1)
- b. Draw the circuit and explain the frequency response of a second order band pass filter. **06** (2 :5 : 1.3.1)
- c. Explain the operation of Mono-stable multi vibrator with relevant diagrams and waveforms. **08** (2 :5 : 1.3.1)

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